

# NTD40N03R

## Power MOSFET 45 Amps, 25 Volts N-Channel DPAK

### Features

- Planar HD3e Process for Fast Switching Performance
- Low  $R_{DS(on)}$  to Minimize Conduction Loss
- Low  $C_{iss}$  to Minimize Driver Loss
- Low Gate Charge
- Optimized for High Side Switching Requirements in High-Efficiency DC-DC Converters
- Pb-Free Packages are Available

### MAXIMUM RATINGS ( $T_J = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	$V_{DSS}$	25	Vdc
Gate-to-Source Voltage – Continuous	$V_{GS}$	$\pm 20$	Vdc
Thermal Resistance – Junction-to-Case	$R_{\theta JC}$	3.0	$^\circ\text{C/W}$
Total Power Dissipation @ $T_C = 25^\circ\text{C}$	$P_D$	50	W
Drain Current	$I_D$	45	A
– Continuous @ $T_C = 25^\circ\text{C}$ , Chip	$I_D$	32	A
– Continuous @ $T_A = 25^\circ\text{C}$ , Limited by Wires	$I_D$	100	A
– Single Pulse ( $t_p \leq 10 \mu\text{s}$ )			
Thermal Resistance – Junction-to-Ambient (Note 1)	$R_{\theta JA}$	71.4	$^\circ\text{C/W}$
– Total Power Dissipation @ $T_A = 25^\circ\text{C}$	$P_D$	2.1	W
– Drain Current – Continuous @ $T_A = 25^\circ\text{C}$	$I_D$	9.2	A
Thermal Resistance – Junction-to-Ambient (Note 2)	$R_{\theta JA}$	100	$^\circ\text{C/W}$
– Total Power Dissipation @ $T_A = 25^\circ\text{C}$	$P_D$	1.5	W
– Drain Current – Continuous @ $T_A = 25^\circ\text{C}$	$I_D$	7.8	A
Operating and Storage Temperature Range	$T_J, T_{stg}$	-55 to 175	$^\circ\text{C}$
Maximum Lead Temperature for Soldering Purposes, 1/8 in from case for 10 seconds	$T_L$	260	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

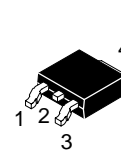
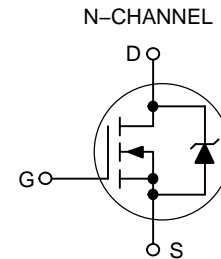
1. When surface mounted to an FR4 board using 0.5 sq. in pad size.
2. When surface mounted to an FR4 board using minimum recommended pad size.



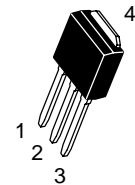
ON Semiconductor®

<http://onsemi.com>

**45 AMPERES, 25 VOLTS**  
 **$R_{DS(on)} = 12.6 \text{ m}\Omega$  (Typ)**

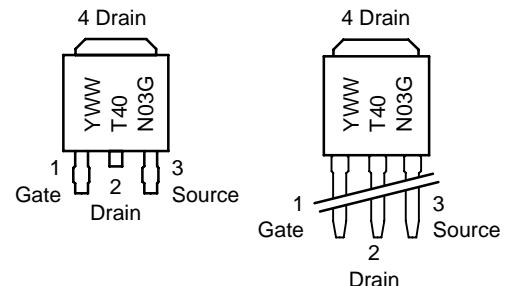


**CASE 369AA**  
**DPAK**  
**(Surface Mount)**  
**STYLE 2**



**CASE 369D**  
**DPAK**  
**(Straight Lead)**  
**STYLE 2**

### MARKING DIAGRAM & PIN ASSIGNMENTS



Y = Year  
WW = Work Week  
T40N03 = Device Code  
G = Pb-Free Package

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# NTD40N03R

## ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Drain-to-Source Breakdown Voltage (Note 3) ( $V_{GS} = 0\text{ Vdc}$ , $I_D = 250\ \mu\text{Adc}$ ) Temperature Coefficient (Positive)	$V_{(br)DSS}$	25 -	28 -	- -	Vdc mV/ $^\circ\text{C}$
Zero Gate Voltage Drain Current ( $V_{DS} = 20\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) ( $V_{DS} = 20\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ , $T_J = 150^\circ\text{C}$ )	$I_{DSS}$	- -	- -	1.0 10	$\mu\text{Adc}$
Gate-Body Leakage Current ( $V_{GS} = \pm 20\text{ Vdc}$ , $V_{DS} = 0\text{ Vdc}$ )	$I_{GSS}$	-	-	$\pm 100$	nAdc

### ON CHARACTERISTICS (Note 3)

Gate Threshold Voltage (Note 3) ( $V_{DS} = V_{GS}$ , $I_D = 250\ \mu\text{Adc}$ ) Threshold Temperature Coefficient (Negative)	$V_{GS(th)}$	1.0 -	1.7 -	2.0 -	Vdc mV/ $^\circ\text{C}$
Static Drain-to-Source On-Resistance (Note 3) ( $V_{GS} = 4.5\text{ Vdc}$ , $I_D = 10\text{ Adc}$ ) ( $V_{GS} = 10\text{ Vdc}$ , $I_D = 10\text{ Adc}$ )	$R_{DS(on)}$	- -	18.6 12.6	23 16.5	m $\Omega$
Forward Transconductance (Note 3) ( $V_{DS} = 10\text{ Vdc}$ , $I_D = 10\text{ Adc}$ )	$g_{FS}$	-	20	-	Mhos

### DYNAMIC CHARACTERISTICS

Input Capacitance	$(V_{DS} = 20\text{ Vdc}$ , $V_{GS} = 0\text{ V}$ , $f = 1\text{ MHz}$ )	$C_{iss}$	-	584	-	$\mu\text{F}$
Output Capacitance		$C_{oss}$	-	254	-	
Transfer Capacitance		$C_{rss}$	-	99	-	

### SWITCHING CHARACTERISTICS (Note 4)

Turn-On Delay Time	$(V_{GS} = 10\text{ Vdc}$ , $V_{DD} = 10\text{ Vdc}$ , $I_D = 10\text{ Adc}$ , $R_G = 3\ \Omega$ )	$t_{d(on)}$	-	4.5	-	ns
Rise Time		$t_r$	-	19.5	-	
Turn-Off Delay Time		$t_{d(off)}$	-	16.7	-	
Fall Time		$t_f$	-	3.5	-	
Gate Charge	$(V_{GS} = 4.5\text{ Vdc}$ , $I_D = 10\text{ Adc}$ , $V_{DS} = 10\text{ Vdc}$ ) (Note 3)	$Q_T$	-	5.78	-	nC
		$Q_1$	-	2.1	-	
		$Q_2$	-	2.5	-	

### SOURCE-DRAIN DIODE CHARACTERISTICS

Forward On-Voltage	$(I_S = 10\text{ Adc}$ , $V_{GS} = 0\text{ Vdc}$ ) (Note 3) $(I_S = 10\text{ Adc}$ , $V_{GS} = 0\text{ Vdc}$ , $T_J = 125^\circ\text{C}$ )	$V_{SD}$	- -	0.85 0.71	1.2 -	Vdc
Reverse Recovery Time	$(I_S = 10\text{ Adc}$ , $V_{GS} = 0\text{ Vdc}$ , $di_S/dt = 100\text{ A}/\mu\text{s}$ ) (Note 3)	$t_{rr}$	-	20.4	-	ns
		$t_a$	-	8.25	-	
		$t_b$	-	12.1	-	
Reverse Recovery Stored Charge		$Q_{RR}$	-	0.007	-	$\mu\text{C}$

3. Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ , Duty Cycle  $\leq 2\%$ .

4. Switching characteristics are independent of operating junction temperatures.

# NTD40N03R

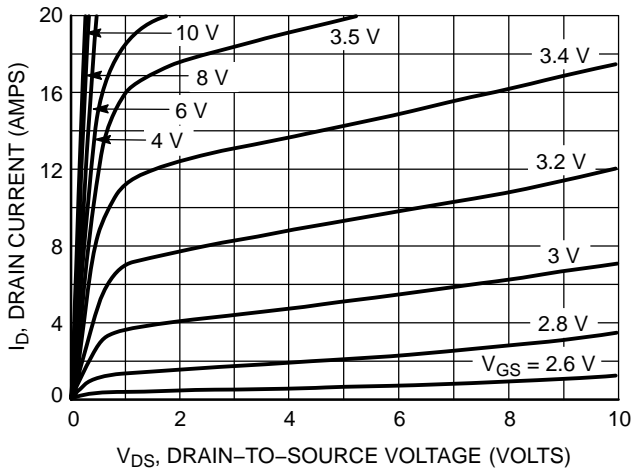


Figure 1. On-Region Characteristics

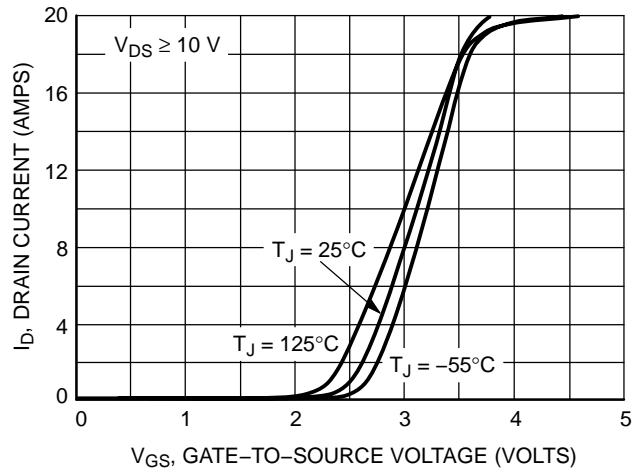


Figure 2. Transfer Characteristics

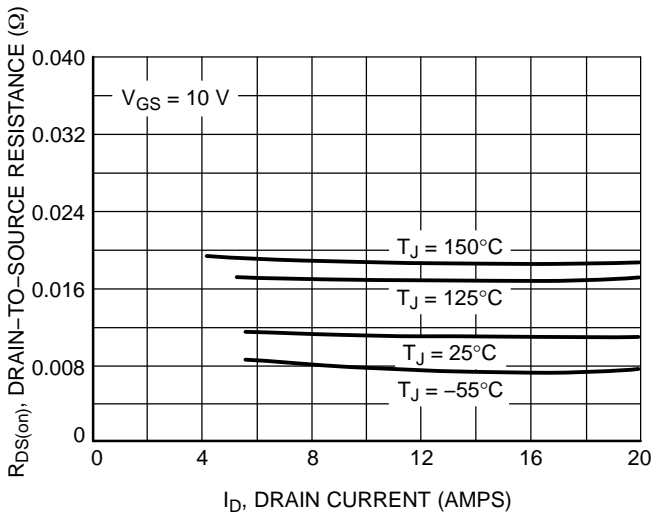


Figure 3. On-Resistance versus Drain Current and Temperature

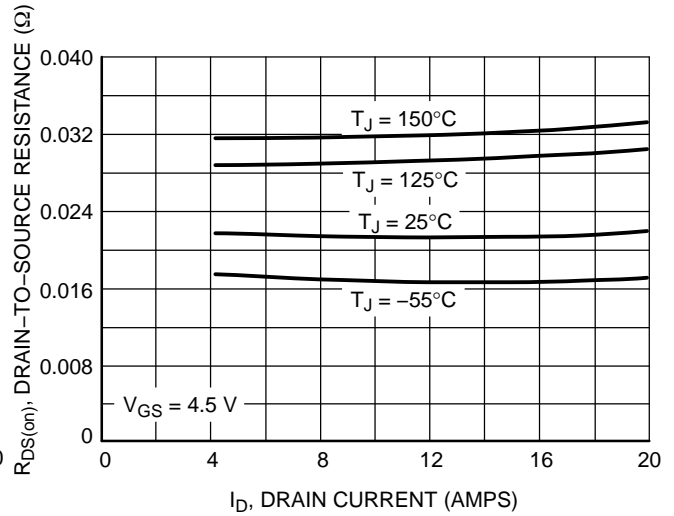


Figure 4. On-Resistance versus Drain Current and Temperature

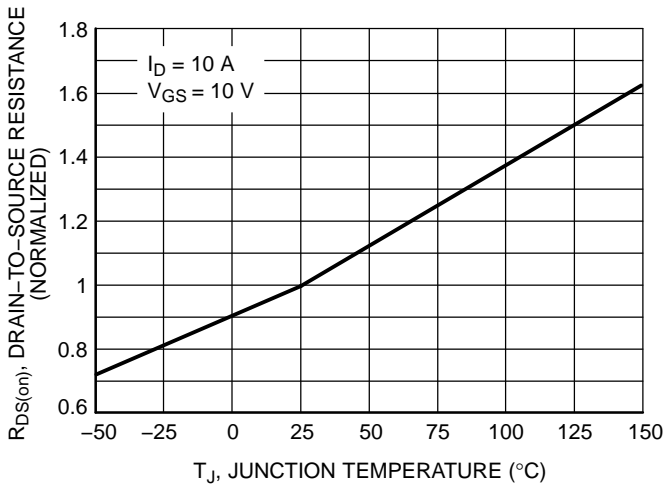


Figure 5. On-Resistance Variation with Temperature

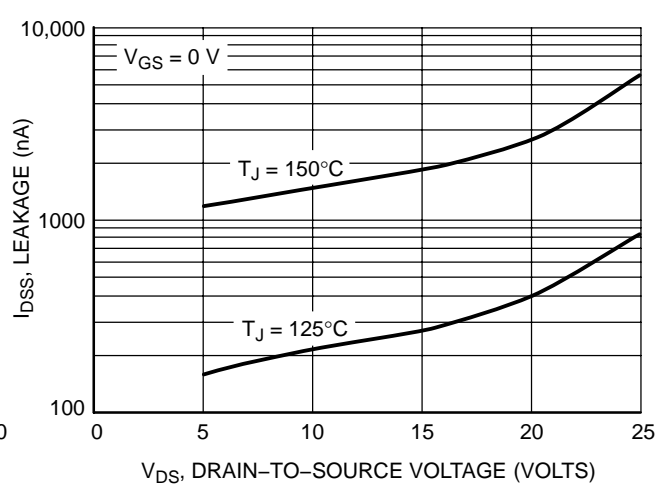
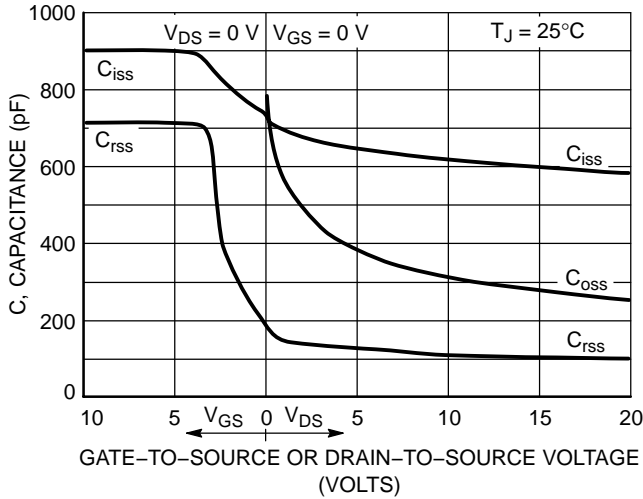
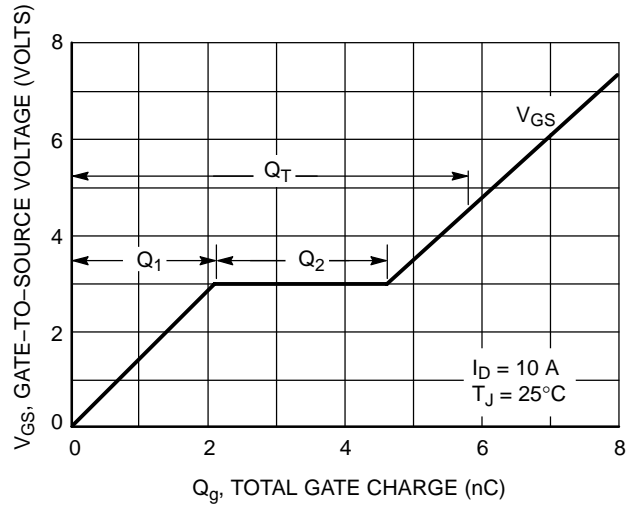


Figure 6. Drain-to-Source Leakage Current versus Voltage

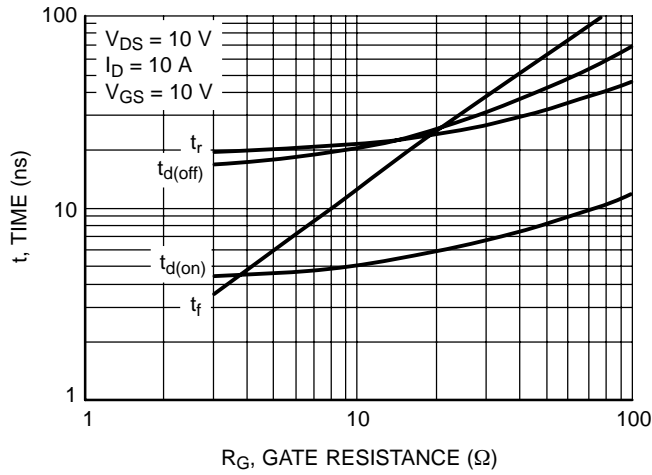
# NTD40N03R



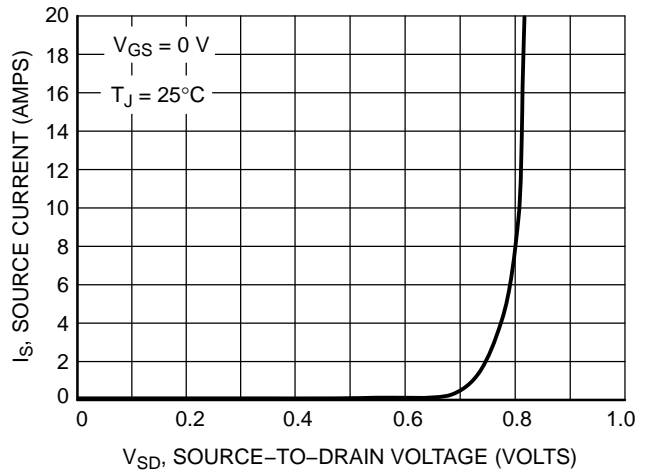
**Figure 7. Capacitance Variation**



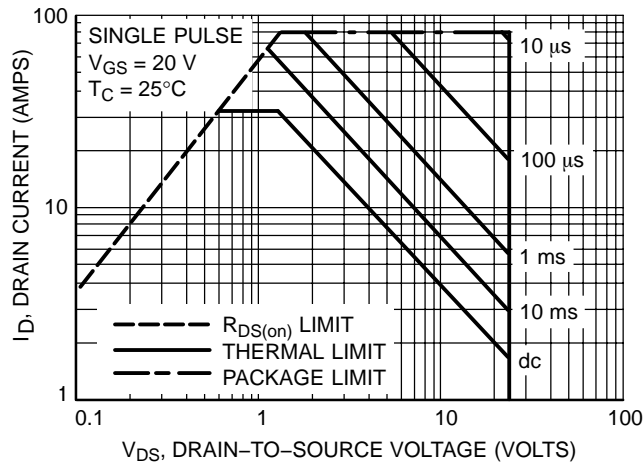
**Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge**



**Figure 9. Resistive Switching Time Variation versus Gate Resistance**



**Figure 10. Diode Forward Voltage versus Current**



**Figure 11. Maximum Rated Forward Biased Safe Operating Area**

# NTD40N03R

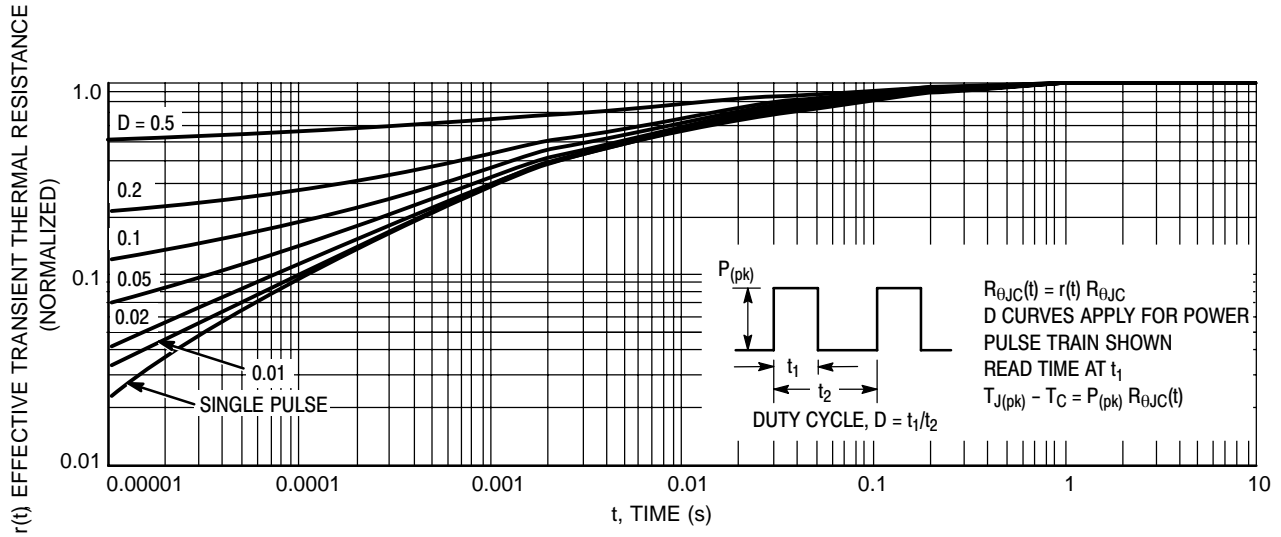


Figure 12. Thermal Response

## ORDERING INFORMATION

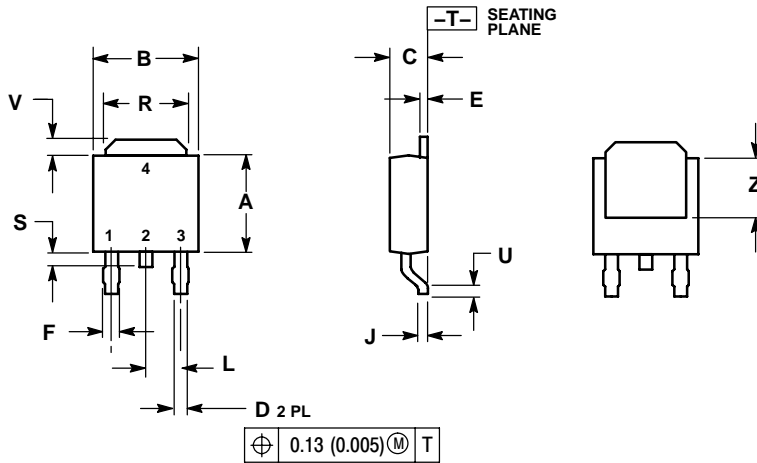
Device	Package	Shipping <sup>†</sup>
NTD40N03R	DPAK	75 Units/Rail
NTD40N03RG	DPAK (Pb-Free)	75 Units/Rail
NTD40N03R-1	DPAK (Straight Lead)	75 Units/Rail
NTD40N03R-1G	DPAK (Straight Lead) (Pb-Free)	75 Units/Rail
NTD40N03RT4	DPAK	2500 Tape & Reel
NTD40N03RT4G	DPAK (Pb-Free)	2500 Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NTD40N03R

## PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE)  
CASE 369AA-01  
ISSUE O

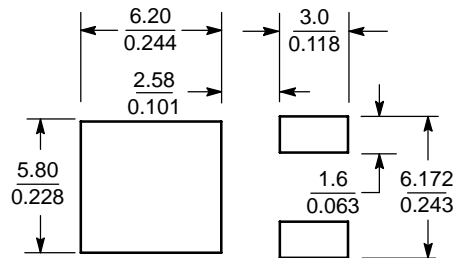


- NOTES:  
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.22
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.025	0.035	0.63	0.88
E	0.018	0.024	0.46	0.61
F	0.033	0.045	0.83	1.14
J	0.018	0.023	0.46	0.58
L	0.090 BSC		2.29 BSC	
R	0.180	0.215	4.57	5.45
S	0.025	0.040	0.63	1.01
U	0.020	---	0.51	---
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

- STYLE 2:  
PIN 1. GATE  
2. DRAIN  
3. SOURCE  
4. DRAIN

## SOLDERING FOOTPRINT\*



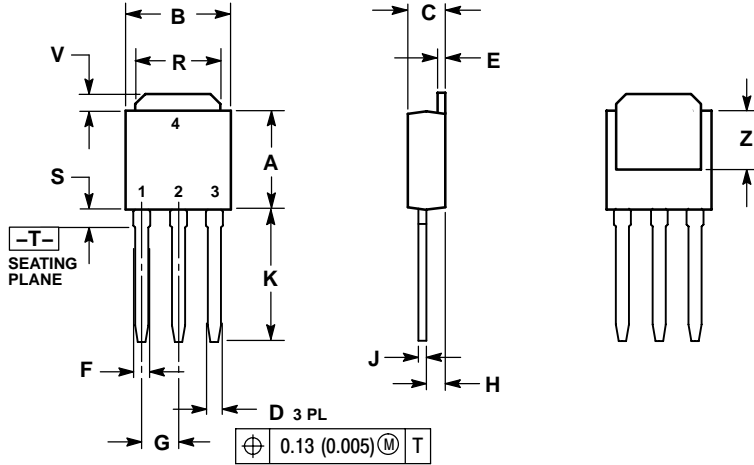
SCALE 3:1  $\left(\frac{\text{mm}}{\text{inches}}\right)$

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# NTD40N03R

## PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE)  
CASE 369D-01  
ISSUE B



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090	BSC	2.29	BSC
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

STYLE 2:

- PIN 1. GATE
- DRAIN
- SOURCE
- DRAIN

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